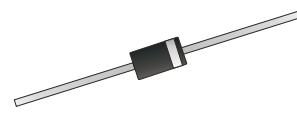


## 1N5820-G Thru. 1N5822-G

**Forward Current: 3.0A**

**Reverse Voltage: 20 to 40V**

**RoHS Device**

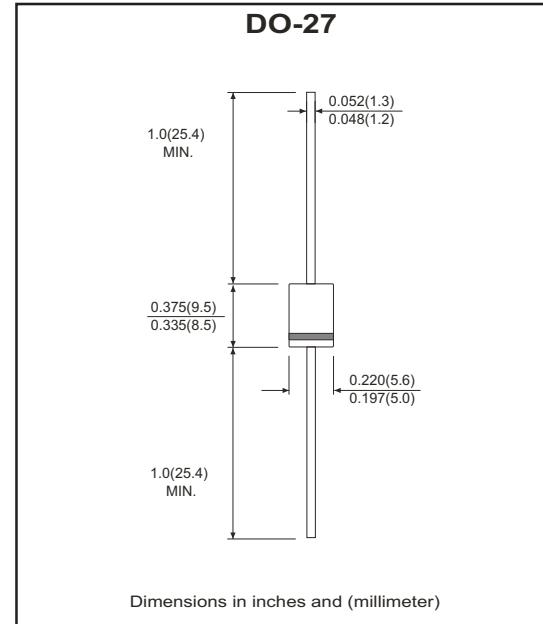


### Features

- Fast switching.
- Low forward voltage, high current capability.
- Low power loss, high efficiency.
- High current surge capability.
- High temperature soldering guaranteed: 250°C/10 seconds, 0.375"(9.5mm) lead length at 5lbs. (2.3kg) tension.

### Mechanical data

- Case: Transfer molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Polarity: Color band denotes cathode end
- Lead: Plated axial lead, solderable per MIL-STD-202E method 208C
- Mounting position: Any
- Weight: 0.042 ounces, 1.19gram



### Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load derate current by 20%.

Parameter	Symbol	1N5820-G	1N5821-G	1N5822-G	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	V
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	V
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	V
Maximum average forward rectified current 0.375"(9.5mm) lead length @T <sub>L</sub> =95°C	I <sub>(AV)</sub>		3.0		A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>		80		A
Maximum forward voltage at 3.0A 9.4A	V <sub>F</sub>	0.475 0.850	0.500 0.900	0.525 0.950	V
Maximum reverse current at rated DC blocking voltage *1 T <sub>A</sub> =25 °C *1 T <sub>A</sub> =100 °C	I <sub>R</sub>		2.0 20		mA
Typical junction capacitance *2	C <sub>J</sub>		250		pF
Typical thermal resistance *3	R <sub>θJA</sub>		40		°C/W
Operating temperature range	T <sub>J</sub>		-55 to +125		°C
Storage temperature range	T <sub>STG</sub>		-55 to +125		°C

NOTES:

1. Pulse test: 300μs pulse width, 1% duty cycle.

2. Measured at 1.0MHz and applied reverse voltage of 4.0Volts.

2. Thermal resistance from junction to ambient, P.C.B. Mounted with 0.375"(9.5mm) lead length with 2.5"×2.5"(63.5×63.5mm) copper pads.

# Schottky Barrier Rectifier

**Comchip**  
SMD Diode Specialist

## RATING AND CHARACTERISTIC CURVES (1N5820-G Thru. 1N5822-G)

Fig.1 Typical Forward Current Derating Curve

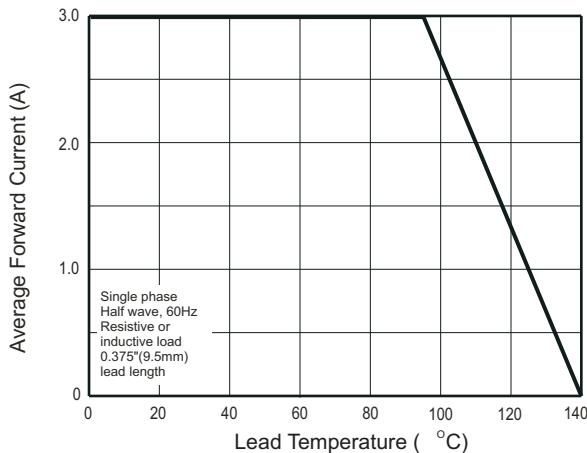


Fig.2 Maximum Non-repetitive Peak Forward Surge Current

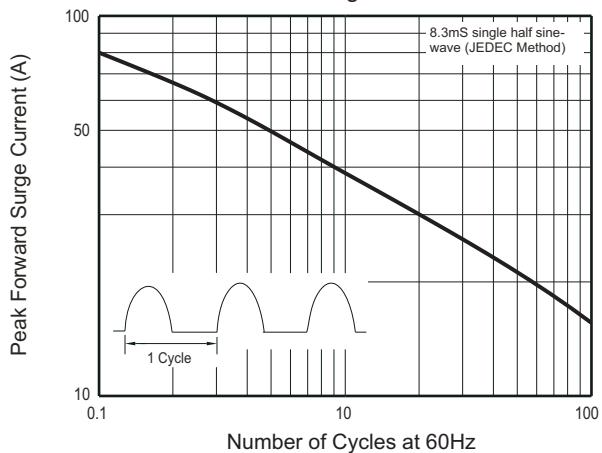


Fig.3 Typical Instantaneous Forward Characteristics

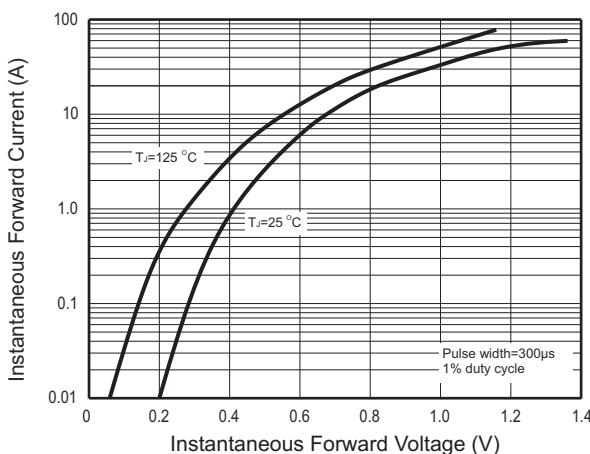


Fig.4 Typical Reverse Characteristics

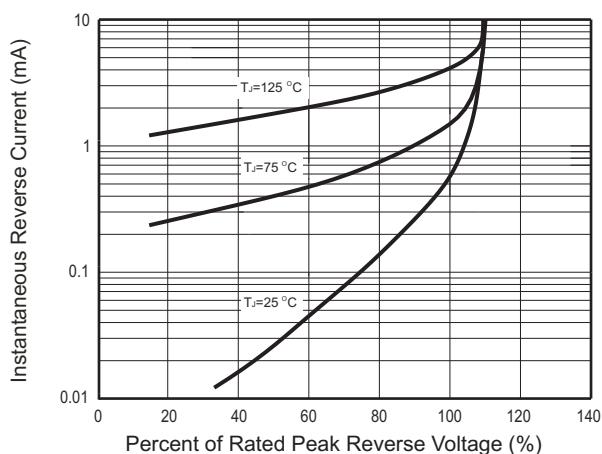


Fig.5 Typical Junction Capacitance

